NSN 5961-01-110-1850

Semiconductor Device Set - Page 1 of 1



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Inclosure Material:
Plastic all transistor
Overall Length:
0.210 inches all transistor
Terminal Length:
0.500 inches all transistor
Overall Height:
0.165 inches all transistor
Overall Width:
0.205 inches all transistor
Internal Configuration:
Junction contact all transistor
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-92 all transistor
Internal Junction Configuration:
Npn all transistor
Component Function Relationship:
Matched
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal all transistor
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
30.0 collector to base voltage/static/emitter open all transistor and 30.0 collector to emitter voltage/static/base open all transistor and 6.0
emitter to base voltage, static, collector open all transistor
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
360.0 milliwatts small-signal input power, common-collector absolute all transistor
Test Data Document:
63409-9237 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 uninsulated wire lead all transistor
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

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